

**2SC3950**

High-Definition CRT Display Video Output Applications

Applications

- High-definition CRT display video output, wide-band amplifier.

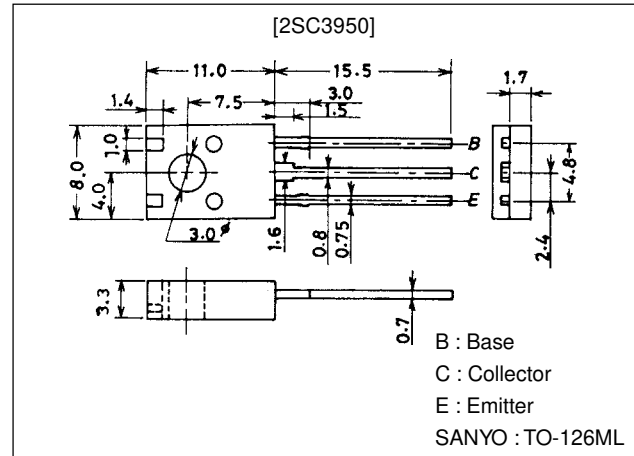
Features

- High f_T : $f_T=2.0\text{GHz}$.
- Large current capacity : $I_C=500\text{mA}$.
- Micaless type : TO-126 plastic package.

Package Dimensions

unit:mm

2042A



Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		30	V
Collector-to-Emitter Voltage	V_{CE0}		20	V
Emitter-to-Base Voltage	V_{EBO}		3	V
Collector Current	I_C		500	mA
Collector Current (Pulse)	I_{CP}		1000	mA
Collector Dissipation	P_C		1.3	W
		$T_c=25^\circ\text{C}$	5	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=20\text{V}, I_E=0$			0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=2\text{V}, I_C=0$			5.0	μA
DC Current Gain	h_{FE1}	$V_{CE}=5\text{V}, I_C=50\text{mA}$	40*		200*	
	h_{FE2}	$V_{CE}=5\text{V}, I_C=100\text{mA}$	20			
Gain-Bandwidth Product	f_T	$V_{CE}=5\text{V}, I_C=100\text{mA}$		2.0		GHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		6.0		pF
Reverse Transfer Capacitance	C_{re}	$V_{CB}=10\text{V}, f=1\text{MHz}$		4.6		pF

* h_{FE1} : The 2SC3950 is classified by 50mA h_{FE} as follows :

40	C	80	60	D	120	100	E	200
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■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

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2SC3950

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=300mA, I_B=30mA$		0.3	0.8	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=300mA, I_B=30mA$		0.9	1.2	V

